

Date Filed: January 28, 2005

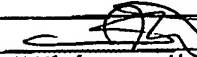
Sheet 1 of 1

Form 1449* INFORMATION DISCLOSURE STATEMENT IN AN APPLICATION	Docket Number: GRC 122.45-US-U1	Application Number: 10/723,976
	Applicants: Torsten Wipiejewski et al.	
	Filing Date: November 26, 2003	Group Art Unit: 2883

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U.S. PATENT DOCUMENTS						
EXAMINER INITIAL	DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
FOREIGN PATENTS						
	DOCUMENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES NO
NON-PATENT DOCUMENTS (Including Author, Title, Date, Periodic Pages, Etc.)						
A			Aimez, V., et al., "Low-energy ion-implantation-induced quantum-well intermixing," IEEE Journal of Selected Topics in Quantum Electronics, 8:870-879, 2002			
A			Allard, M., et al., "Temperature determination in optoelectronic waveguide modulators," Journal of Lightwave Technology, 18:813-818, 2000			
A			Bian, Z., et al., "High-power operation of electro-absorption modulators," Applied Physics Letters, 83:3605-3607, 2003			
A			Claassen, M., et al., "Two-section electro-absorption modulator with negative chirp at low insertion loss," Electronics Lett., 32:2121-2122, 1996			
A			Hamoudi, A., et al., "Controlled disordering of compressively strained InGaAsP multiple quantum wells under SiO ₂ P encapsulant and application to laser-modulator integration," Journal of Applied Physics, 78:5638-5641, 1995			
A			Jasmin, S., et al., "Diluted- and distributed- absorption microwave waveguide photodiodes for high efficiency and high power," IEEE Transactions on Microwave Theory and Techniques, 45:1337-1341, 1997			
A			Mason, B., et al., "40-Gb/s Tandem Electro-absorption Modulator," IEEE Photon. Techn. Lett., 14:27-29, 2002			
A			Murthy, S., et al., "A novel monolithic distributed traveling-wave photodetector with parallel optical feed," IEEE Photonics Technology Letters, 12:681-683, 2000			
A			Nespoli, A., et al., "Analysis of failure mechanisms in velocity-matched distributed photodetectors," IEEE Proc. Optoelectron, 146:25-30, 1999			
A			Shi, J.-W., et al., "Theory and design of a tapered line distributed photodetector," Journal of Lightwave Technology, 20:1942-1950, 2002			
A			Wipiejewski, T., et al., "Improved Performance of Vertical-Cavity Surface-Emitting Laser Diodes with Au-Plated Heat Spreading Layer," Electronics Lett., 31:279-281, 1995			
A			Wipiejewski, T., et al., "Monolithic Integration of a Widely Tunable Laser Diode with a High Speed Electro-Absorption Modulator," 52 nd ECTC, San Diego, May 2002			

EXAMINER: 	DATE CONSIDERED: 6/2005
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form for next communication to the Applicant.	

*Substitute Disclosure Statement Form (PTO-1449)

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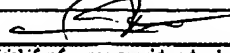
G&C 122.45-US-U1

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